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APPLICATION NO.	F	ILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO	
09/903,339		07/10/2001	Naoto Kusumoto	07977-010004	8970	
26171	7590	02/12/2004		EXAMINER		
FISH & RI			DOAN, THERESA T			
1425 K STR 11TH FLOC		V.		ART UNIT PAPER NUMBER		
		20005-3500		2814		
				DATE MAIL ED: 02/12/200	4	

Please find below and/or attached an Office communication concerning this application or proceeding.

				Ar-
		Application No.	Applicant(s)	.,
		09/903,339	KUSUMOTO ET AL.	
	Office Action Summary	Examiner	Art Unit	
		Theresa T Doan	2814	
Period fo	The MAILING DATE of this communication app	pears on the cover sheet with	the correspondenc address	
A SHOTHE No. 1 the after after fino Failu Anyr	ORTENED STATUTORY PERIOD FOR REPLY MAILING DATE OF THIS COMMUNICATION. Is ions of time may be available under the provisions of 37 CFR 1.13 SIX (6) MONTHS from the mailing date of this communication. Period for reply specified above is less than thirty (30) days, a reply period for reply is specified above, the maximum statutory period to reply within the set or extended period for reply will, by statute eply received by the Office later than three months after the mailing of patent term adjustment. See 37 CFR 1.704(b).	36(a). In no event, however, may a rep y within the statutory minimum of thirty vill apply and will expire SIX (6) MONTI , cause the application to become ABA	ly be timely filed (30) days will be considered timely. IS from the mailing date of this communication NDONED (35 U.S.C. § 133).	n.
1)🖂	Responsive to communication(s) filed on 15.	January 2004 .		
2a)□	·	is action is non-final.		
3) Dispositi	Since this application is in condition for allowationsed in accordance with the practice under on of Claims			is
·	Claim(s) 1-30 is/are pending in the application	1,		
•	4a) Of the above claim(s) <u>1-24</u> is/are withdrawr			
	Claim(s) is/are allowed.			
·	Claim(s) <u>25-30</u> is/are rejected.			
•	Claim(s) is/are objected to.			
•	Claim(s) are subject to restriction and/o	r election requirement.		
Applicati	on Papers			
9)□	The specification is objected to by the Examine	r.		
10)[The drawing(s) filed on is/are: a)☐ acce			
	Applicant may not request that any objection to the			
11) 🗌	The proposed drawing correction filed on		sapproved by the Examiner.	
_	If approved, corrected drawings are required in re	•		
,—	The oath or declaration is objected to by the Ex	aminer.		
_	ınder 35 U.S.C. §§ 119 and 120			
•	Acknowledgment is made of a claim for foreign	n priority under 35 U.S.C. §	119(a)-(d) or (f).	
a)[☑ All b)☐ Some * c)☐ None of:			
	1. Certified copies of the priority document			
	2. Certified copies of the priority document			
* 5	3. Copies of the certified copies of the prio application from the International Bu See the attached detailed Office action for a list	reau (PCT Rule 17.2(a)).		
14) 🗌 A	Acknowledgment is made of a claim for domesti	ic priority under 35 U.S.C. §	119(e) (to a provisional applicat	tion).
) The translation of the foreign language pro Acknowledgment is made of a claim for domest			
Attachmen	t(s)			
2) Notic	e of References Cited (PTO-892) te of Draftsperson's Patent Drawing Review (PTO-948) mation Disclosure Statement(s) (PTO-1449) Paper No(s) <u>1</u>	5) Notice of In	ummary (PTO-413) Paper No(s) formal Patent Application (PTO-152)	

Art Unit: 2814

DETAILED ACTION

Request for Continued Examination

1. A request for continued examination under 37 CFR 1.114, including the fee set forth in 37 CFR 1.17(e), was filed in this application after final rejection. Since this application is eligible for continued examination under 37 CFR 1.114, and the fee set forth in 37 CFR 1.17(e) has been timely paid, the finality of the previous Office action has been withdrawn pursuant to 37 CFR 1.114. Applicant's submission filed on 02/15/04 has been entered. An action on the RCE follows.

Claim Rejections - 35 USC § 102

2. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(e) the invention was described in a patent granted on an application for patent by another filed in the United States before the invention thereof by the applicant for patent, or on an international application by another who has fulfilled the requirements of paragraphs (1), (2), and (4) of section 371(c) of this title before the invention thereof by the applicant for patent.

The changes made to 35 U.S.C. 102(e) by the American Inventors Protection Act of 1999 (AIPA) do not apply to the examination of this application as the application being examined was not (1) filed on or after November 29, 2000, or (2) voluntarily published under 35 U.S.C. 122(b). Therefore, this application is examined under 35 U.S.C. 102(e) prior to the amendment by the AIPA (pre-AIPA 35 U.S.C. 102(e)).

3. Claims 25-27 are rejected under 35 U.S.C. 102(e) as being anticipated by Zhang et al. (5,508,209) as previous cited.

Art Unit: 2814

Zhang et al. teach in figures 5A-5F a method of manufacturing a semiconductor device comprising the steps of:

forming an amorphous silicon semiconductor film 203 over a substrate 201;

irradiating the amorphous silicon semiconductor film with a second harmonic of a continuous wave laser comprising Nd which is an Nd:YAG laser to crystallize the amorphous semiconductor film (column 9, lines 3-10); and

patterning the crystallized semiconductor film 203 to form an active layer including at least a channel formation region (see figure 5C).

Double Patenting

4. The nonstatutory double patenting rejection is based on a judicially created doctrine grounded in public policy (a policy reflected in the statute) so as to prevent the unjustified or improper timewise extension of the "right to exclude" granted by a patent and to prevent possible harassment by multiple assignees. See *In re Goodman*, 11 F.3d 1046, 29 USPQ2d 2010 (Fed. Cir. 1993); *In re Longi*, 759 F.2d 887, 225 USPQ 645 (Fed. Cir. 1985); *In re Van Ornum*, 686 F.2d 937, 214 USPQ 761 (CCPA 1982); *In re Vogel*, 422 F.2d 438, 164 USPQ 619 (CCPA 1970);and, *In re Thorington*, 418 F.2d 528, 163 USPQ 644 (CCPA 1969).

A timely filed terminal disclaimer in compliance with 37 CFR 1.321(c) may be used to overcome an actual or provisional rejection based on a nonstatutory double patenting ground provided the conflicting application or patent is shown to be commonly owned with this application. See 37 CFR 1.130(b).

Effective January 1, 1994, a registered attorney or agent of record may sign a terminal disclaimer. A terminal disclaimer signed by the assignee must fully comply with 37 CFR 3.73(b).

5. Claims 25-30 are rejected under the judicially created doctrine of obviousness-type double patenting as being unpatentable over claims 17-21, 22-27, 34-43, 48-56 and 61-80 of U. S. Patent No. 6,204,099. Although the conflicting claims are not identical, they are not patentably distinct from each other because as follows: both U.S.

Page 4

Art Unit: 2814

Patent and instant application claimed a method of manufacturing a semiconductor layer comprises amorphous silicon. Moreover, the claims 61-80 in the U.S. No. 6,204,099 are either narrower version of the claims of the instant application or obvious variations thereof. For example, claims 63 and 68 in U.S. No. 6,204,099 "... said semiconductor film comprises amorphous silicon (claim 63)" and whereas claim 26 in the instant application claims "... wherein said amorphous semiconductor film comprises amorphous silicon", that shows no different meaning between these two elements. The facts are that the claims of the U. S. Patent No. 6,204,099 and instant application have claimed the same goal and are not distinguished from each other.

Response to Arguments

- 6. Applicant argues that "Zhang summarily dismisses a continuous oscillated laser as a non-preferred embodiment and then provides examples of only the preferred embodiment; namely the pulse laser". This argument is not persuasive because Zhang (column 9, lines 1-7) clearly discloses that "The laser does not need to be limited to an excimer laser, and other lasers are also usable", including "a continuous oscillated laser", but "a pulsed laser" is preferred. Therefore, Zhang does not dismiss the use of "a continuous oscillated laser" as asserted by Applicant, but rather, Zhang suggest the use of both "a continuous oscillated laser" and "a pulsed laser", but "a pulsed laser" is preferred.
- 7. Regarding the rejection under obviousness-type double patenting, Applicant's argument that Kusumoto does not recite the step of "patterning the crystallized

Art Unit: 2814

6,204,099 is still proper.

semiconductor film to form an active layer including at least a channnel formation region". This argument is not persuasive because the above limitations are disclosed in claim 78 of Kusumoto. Therefore, the double patenting as it applies to U.S. Patent No.

The rest of applicant's arguments, addressed to the amended claims are considered in the rejections shown above.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Theresa T Doan whose telephone number is (571) 272-1704. The examiner can normally be reached on Monday to Thursday from 8:00AM - 6:00PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, WAEL FAHMY can be reached on (571) 272-1705. The fax phone number for the organization where this application or proceeding is assigned is (703) 872-9306.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (571) 272-1562.

TD February 3, 2004.

PHAT X. CAO Primary Examiner. Page 5